

## WEST

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Entry 1 of 19

File: JPAB

Jan 22, 1999

PUB-NO: JP411017142A

DOCUMENT-IDENTIFIER: JP 11017142 A

TITLE: SEMICONDUCTOR ELEMENT AND MANUFACTURE THEREOF

PUBN-DATE: January 22, 1999

INVENTOR-INFORMATION:

NAME

IDA, JIRO

INT-CL (IPC): H01L 27/108; H01L 21/8242; H01L 21/768

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Claims](#) [KIND](#) [Clip Img](#) [Image](#) 2. Document ID: JP 07005310 A

Entry 2 of 19

File: JPAB

Jan 10, 1995

PUB-NO: JP407005310A

DOCUMENT-IDENTIFIER: JP 07005310 A

TITLE: WEAR RESISTANT OPTICAL STACK

PUBN-DATE: January 10, 1995

INVENTOR-INFORMATION:

NAME

ENGEL, TIMOTHY C

INT-CL (IPC): G02B 5/08; A47G 1/00; C23C 14/06; C23C 14/08; C23C 28/04

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Claims](#) [KIND](#) [Image](#) 3. Document ID: JP 07099174 A

Entry 3 of 19

File: JPAB

Apr 11, 1995

PUB-NO: JP407099174A

DOCUMENT-IDENTIFIER: JP 07099174 A

TITLE: CLEANING METHOD FOR THIN-FILM FORMING APPARATUS

PUBN-DATE: April 11, 1995

INVENTOR-INFORMATION:

NAME

MORI, ISAMU

FUJII, TADASHI

NAKAGAWA, SHINSUKE

ARAI, HIROMICHI

INT-CL (IPC): H01L 21/304; B08B 7/00; H01L 21/285; C11D 3/02

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4. Document ID: JP 10178159 A

Entry 4 of 19

File: JPAB

Jun 30, 1998

PUB-NO: JP410178159A

DOCUMENT-IDENTIFIER: JP 10178159 A

TITLE: SEMICONDUCTOR DEVICE HAVING CAPACITOR AND MANUFACTURE THEREOF

PUBN-DATE: June 30, 1998

INVENTOR-INFORMATION:

NAME

TAKAHASHI, HIDENORI

INT-CL (IPC): H01L 27/108; H01L 21/8242; H01L 21/318; H01L 27/04; H01L 21/822; H01L 27/115; H01L 21/8247; H01L 29/788; H01L 29/792

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#)

5. Document ID: JP 10064917 A

Entry 5 of 19

File: JPAB

Mar 6, 1998

PUB-NO: JP410064917A

DOCUMENT-IDENTIFIER: JP 10064917 A

TITLE: SILICON WAFER AND ITS MANUFACTURING METHOD

PUBN-DATE: March 6, 1998

INVENTOR-INFORMATION:

NAME

TAKAMIZAWA, SHOICHI

KOBAYASHI, NORIHIRO

INT-CL (IPC): H01L 21/322

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#)

6. Document ID: JP 10039334 A

Entry 6 of 19

File: JPAB

Feb 13, 1998

PUB-NO: JP410039334A

DOCUMENT-IDENTIFIER: JP 10039334 A

TITLE: ARRAY SUBSTRATE AND LIQUID CRYSTAL DISPLAY DEVICE

PUBN-DATE: February 13, 1998

INVENTOR-INFORMATION:

NAME

NAKAMURA, KENJIRO

FUKUDA, KAICHI

INT-CL (IPC): G02F 1/136; G02F 1/1333; H01L 29/786

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#) 7. Document ID: JP 09232317 A

Entry 7 of 19

File: JPAB

Sep 5, 1997

PUB-NO: JP409232317A

DOCUMENT-IDENTIFIER: JP 09232317 A

TITLE: FORMING METHOD OF SEMICONDUCTOR DEVICE

PUBN-DATE: September 5, 1997

INVENTOR-INFORMATION:

NAME

CHIYOU, KOUYUU

MURAKAMI, AKANE

INT-CL (IPC): H01L 21/3205; H01L 21/265; H01L 21/28; H01L 29/786

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#) 8. Document ID: JP 08293607 A

Entry 8 of 19

File: JPAB

Nov 5, 1996

PUB-NO: JP408293607A

DOCUMENT-IDENTIFIER: JP 08293607 A

TITLE: SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE AND MANUFACTURING METHOD THEREOF

PUBN-DATE: November 5, 1996

INVENTOR-INFORMATION:

NAME

TOIDA, TAKASHI

AIHARA, KATSUYOSHI

INT-CL (IPC): H01L 29/786; C23F 1/00; H01L 21/3065; H01L 21/318

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#) 9. Document ID: JP 08008437 A

Entry 9 of 19

File: JPAB

Jan 12, 1996

PUB-NO: JP408008437A

DOCUMENT-IDENTIFIER: JP 08008437 A

TITLE: SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE AND ITS MANUFACTURE

PUBN-DATE: January 12, 1996

INVENTOR-INFORMATION:

NAME

TOIDA, TAKASHI

AIHARA, KATSUYOSHI

INT-CL (IPC): H01L 29/786; H01L 21/336

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Claims](#) [KWC](#) [Clip Img](#) [Image](#) 10. Document ID: JP 08097211 A

Entry 10 of 19

File: JPAB

Apr 12, 1996

PUB-NO: JP408097211A

DOCUMENT-IDENTIFIER: JP 08097211 A

TITLE: SILICON WIRING STRUCTURE AND ITS PATTERNING METHOD

PUBN-DATE: April 12, 1996

INVENTOR-INFORMATION:

NAME

TATSUMI, TETSUYA

INT-CL (IPC): H01L 21/3205

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Terms	Documents
silicon oxynitride and (silicon and (oxide or dioxide)) and thin and film	19

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11

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Entry 11 of 19

File: JPAB

May 28, 1992

PUB-NO: JP404155969A

DOCUMENT-IDENTIFIER: JP 04155969 A

TITLE: SEMICONDUCTOR NONVOLATILE STORAGE AND ITS MANUFACTURE

PUBN-DATE: May 28, 1992

INVENTOR- INFORMATION:

NAME

SATTO, NENSEI

INT-CL (IPC): H01L 29/788; H01L 29/792

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Claims](#) [KMD](#) [Clip Img](#) [Image](#) 12. Document ID: JP 03193878 A

Entry 12 of 19

File: JPAB

Aug 23, 1991

PUB-NO: JP403193878A

DOCUMENT-IDENTIFIER: JP 03193878 A

TITLE: PRODUCTION OF SEMICONDUCTOR DEVICE

PUBN-DATE: August 23, 1991

INVENTOR- INFORMATION:

NAME

TOKI, MASAHIKO

TAKEI, MICHIKO

OIWA, KIYOSHI

INT-CL (IPC): C23C 16/50; H01L 21/205; H01L 21/31

[Full](#) [Title](#) [Citation](#) [Front](#) [Review](#) [Classification](#) [Date](#) [Reference](#) [Claims](#) [KMD](#) [Image](#) 13. Document ID: JP 03017269 A

Entry 13 of 19

File: JPAB

Jan 25, 1991

PUB-NO: JP403017269A

DOCUMENT-IDENTIFIER: JP 03017269 A

TITLE: PRODUCTION OF THIN FILM OF SILICON OXYNITRIDE

PUBN-DATE: January 25, 1991

INVENTOR-INFORMATION:

NAME

KAMATA, TAKESHI

KITAGAWA, MASATOSHI

HIRAO, TAKASHI

INT-CL (IPC): C23C 16/30; H01L 21/318

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#)

14. Document ID: JP 02135754 A

Entry 14 of 19

File: JPAB

May 24, 1990

PUB-NO: JP402135754A

DOCUMENT-IDENTIFIER: JP 02135754 A

TITLE: MANUFACTURE OF SEMICONDUCTOR SUBSTRATE

PUBN-DATE: May 24, 1990

INVENTOR-INFORMATION:

NAME

ITO, HIDEJI

INT-CL (IPC): H01L 21/76

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#)

15. Document ID: JP 58122884 A

Entry 15 of 19

File: JPAB

Jul 21, 1983

PUB-NO: JP358122884A

DOCUMENT-IDENTIFIER: JP 58122884 A

TITLE: HEAT-SENSITIVE RECORDING HEAD

PUBN-DATE: July 21, 1983

INVENTOR-INFORMATION:

NAME

KITA, YOSHIAKI

ANDO, HISASHI

INT-CL (IPC): B41J 3/20; H01L 49/00

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KOMC](#) | [Clip Img](#) | [Image](#)

16. Document ID: JP 01308080 A

Entry 16 of 19

File: JPAB

Dec 12, 1989

PUB-NO: JP401308080A

DOCUMENT-IDENTIFIER: JP 01308080 A

TITLE: SEMICONDUCTOR NONVOLATILE MEMORY

PUBN-DATE: December 12, 1989

INVENTOR- INFORMATION:

NAME

KOJIMA, YOSHIKAZU

INT-CL (IPC): H01L 29/78

<a href="#">Full</a>	<a href="#">Title</a>	<a href="#">Citation</a>	<a href="#">Front</a>	<a href="#">Review</a>	<a href="#">Classification</a>	<a href="#">Date</a>	<a href="#">Reference</a>	<a href="#">Claims</a>	<a href="#">KOMC</a>	<a href="#">Clip Img</a>	<a href="#">Image</a>
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17. Document ID: JP 01268060 A

Entry 17 of 19

File: JPAB

Oct 25, 1989

PUB-NO: JP401268060A

DOCUMENT-IDENTIFIER: JP 01268060 A

TITLE: THIN FILM TRANSISTOR

PUBN-DATE: October 25, 1989

INVENTOR- INFORMATION:

NAME

HIRANAKA, KOICHI

INT-CL (IPC): H01L 29/78; H01L 27/12

<a href="#">Full</a>	<a href="#">Title</a>	<a href="#">Citation</a>	<a href="#">Front</a>	<a href="#">Review</a>	<a href="#">Classification</a>	<a href="#">Date</a>	<a href="#">Reference</a>	<a href="#">Claims</a>	<a href="#">KOMC</a>	<a href="#">Clip Img</a>	<a href="#">Image</a>
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18. Document ID: JP 01220839 A

Entry 18 of 19

File: JPAB

Sep 4, 1989

PUB-NO: JP401220839A

DOCUMENT-IDENTIFIER: JP 01220839 A

TITLE: SEMICONDUCTOR DEVICE

PUBN-DATE: September 4, 1989

INVENTOR- INFORMATION:

NAME

FUJIHIRA, MITSUAKI

OKAZAKI, NAOTO

INT-CL (IPC): H01L 21/60

<a href="#">Full</a>	<a href="#">Title</a>	<a href="#">Citation</a>	<a href="#">Front</a>	<a href="#">Review</a>	<a href="#">Classification</a>	<a href="#">Date</a>	<a href="#">Reference</a>	<a href="#">Claims</a>	<a href="#">KOMC</a>	<a href="#">Clip Img</a>	<a href="#">Image</a>
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19. Document ID: JP 63058959 A

Entry 19 of 19

File: JPAB

Mar 14, 1988

PUB-NO: JP363058959A

DOCUMENT-IDENTIFIER: JP 63058959 A

TITLE: FIELD-EFFECT TYPE SEMICONDUCTOR DEVICE WITH CAPACITOR

PUBN-DATE: March 14, 1988

INVENTOR- INFORMATION:

NAME

SADAHIRO, SHIGEKI

INT-CL (IPC): H01L 27/10; H01L 27/04; H01L 29/78

[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Claims](#) | [KMC](#) | [Clip Img](#) | [Image](#)

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Terms	Documents
silicon oxynitride and (silicon and (oxide or dioxide)) and thin and film	19

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